

Dynamic Characteristic

APT40GT60BR

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$ $f = 1MHz$	-	2190	-	pF
C_{oes}	Output Capacitance		-	220	-	
C_{res}	Reverse Transfer Capacitance		-	130	-	
V_{GEP}	Gate-to-Emitter Plateau Voltage	Gate Charge $V_{GE} = 15V$ $V_{CE} = 300V$ $I_C = 40A$	-	8.0	-	V
Q_g	Total Gate Charge ^③		-	200	-	nC
Q_{ge}	Gate-Emitter Charge		-	12	-	
Q_{gc}	Gate-Collector Charge		-	86	-	
SSOA	Switching Safe Operating Area	$T_J = 150^\circ C, R_G = 5\Omega, V_{GE} = 15V, L = 100\mu H, V_{CE} = 600V$	160			A
$t_{d(on)}$	Turn-On Delay Time	Inductive Switching (25°C) $V_{CC} = 400V$ $V_{GE} = 15V$ $I_C = 40A$ $R_G = 5\Omega$ $T_J = +25^\circ C$	-	12	-	ns
t_r	Current Rise Time		-	36	-	
$t_{d(off)}$	Turn-Off Delay Time		-	124	-	
t_f	Current Fall Time		-	55	-	μJ
E_{on1}	Turn-On Switching Energy ^④		-	-	-	
E_{on2}	Turn-On Switching Energy ^⑤		-	945	-	
E_{off}	Turn-Off Switching Energy ^⑥	-	828	-		
$t_{d(on)}$	Turn-On Delay Time	Inductive Switching (125°C) $V_{CC} = 400V$ $V_{GE} = 15V$ $I_C = 40A$ $R_G = 5\Omega$ $T_J = +125^\circ C$	-	12	-	ns
t_r	Current Rise Time		-	33	-	
$t_{d(off)}$	Turn-Off Delay Time		-	165	-	
t_f	Current Fall Time		-	58	-	μJ
E_{on1}	Turn-On Switching Energy ^④		-	-	-	
E_{on2}	Turn-On Switching Energy ^⑤		-	1342	-	
E_{off}	Turn-Off Switching Energy ^⑥	-	1150	-		

Thermal and Mechanical Characteristics

Symbol	Characteristic / Test Conditions	Min	Typ	Max	Unit
$R_{\theta JC}$	Junction to Case (IGBT)	-	-	0.36	°C/W
$R_{\theta JC}$	Junction to Case (DIODE)	-	-	N/A	
W_T	Package Weight	-	6.1	-	g
Torque	Terminals and Mounting Screws	-	-	10	in-lbf
		-	-	1.1	N·m
$V_{isolation}$	RMS Voltage (50-60Hz Sinusoidal Waveform from Terminals to Mounting Base for 1 Min.)	2500	-	-	Volts

① Repetitive Rating: Pulse width limited by maximum junction temperature.

② For Combi devices, I_{ces} includes both IGBT and FRED leakages.

③ See MIL-STD-750 Method 3471.

④ E_{on1} is the clamped inductive turn-on energy of the IGBT only, without the effect of a commutating diode reverse recovery current adding to z a the IGBT turn-on loss. Tested in inductive switching test circuit shown in figure 21, but with a Silicon Carbide diode.

⑤ E_{on2} is the clamped inductive turn-on energy that includes a commutating diode reverse recovery current in the IGBT turn-on switching loss. (See Figures 21, 22.)

⑥ E_{off} is the clamped inductive turn-off energy measured in accordance with JEDEC standard JESD24-1. (See Figures 21, 23.)

⑦ R_G is external gate resistance not including gate driver impedance.

Microsemi reserves the right to change, without notice, the specifications and information contained herein.

Typical Performance Curves

APT40GT60BR

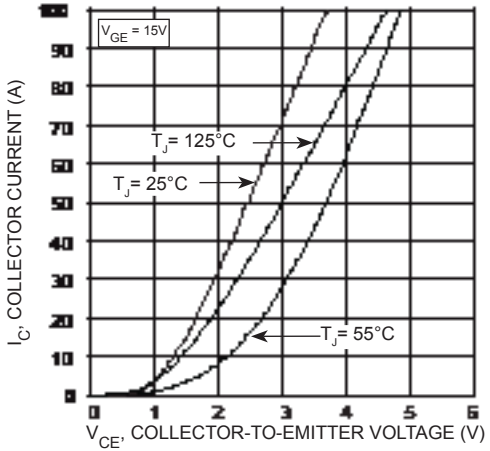


FIGURE 1, Output Characteristics ($T_J = 25^\circ\text{C}$)

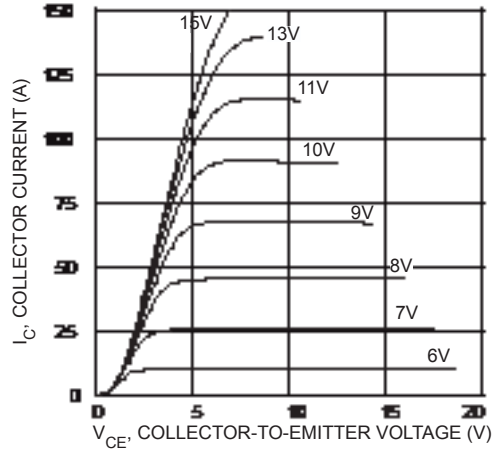


FIGURE 2, Output Characteristics ($T_J = 25^\circ\text{C}$)

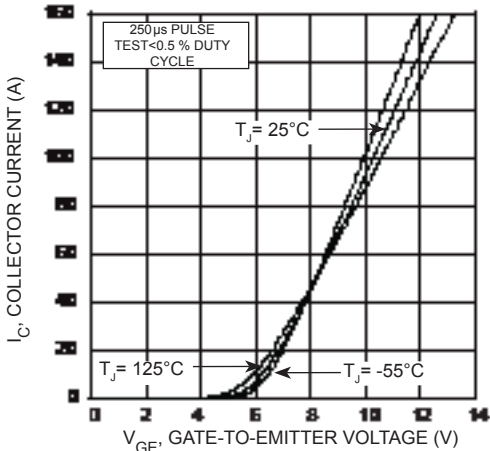


FIGURE 3, Transfer Characteristics

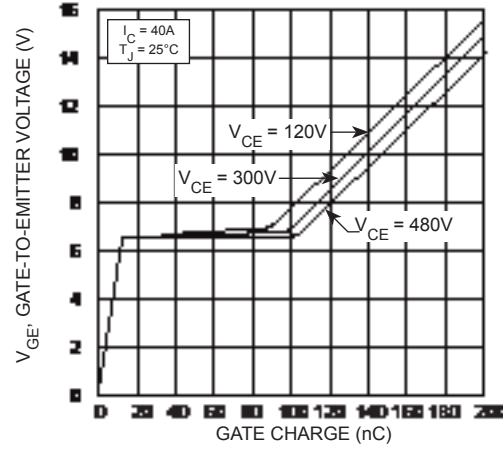


FIGURE 4, Gate charge

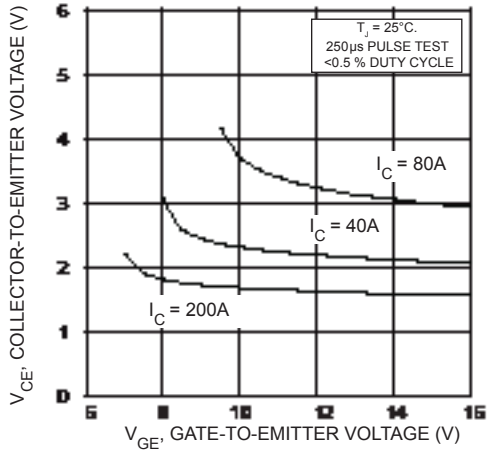


FIGURE 5, On State Voltage vs Gate-to-Emitter Voltage

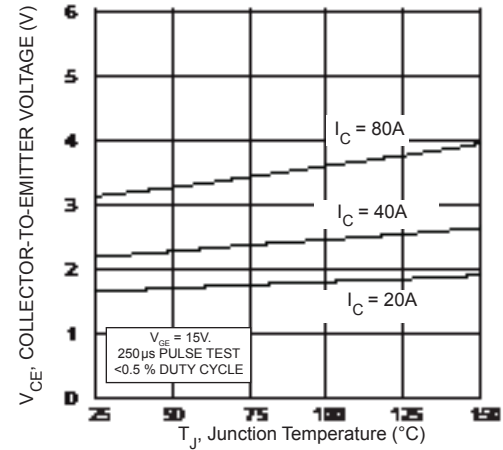


FIGURE 6, On State Voltage vs Junction Temperature

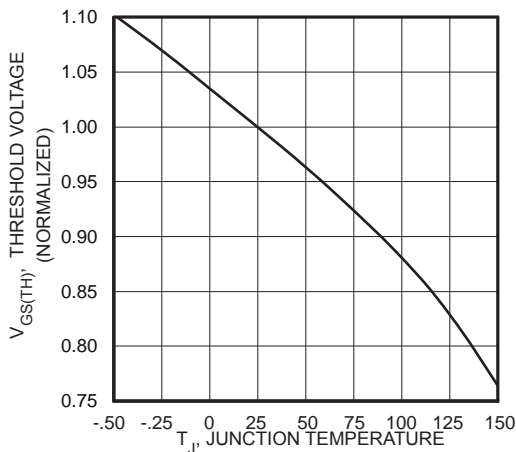


FIGURE 7, Threshold Voltage vs Junction Temperature

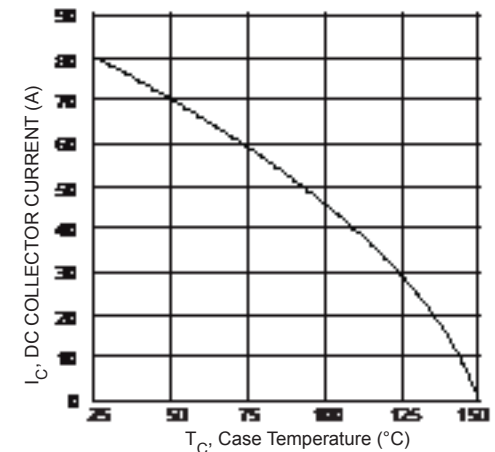


FIGURE 8, DC Collector Current vs Case Temperature

Typical Performance Curves

APT40GT60BR

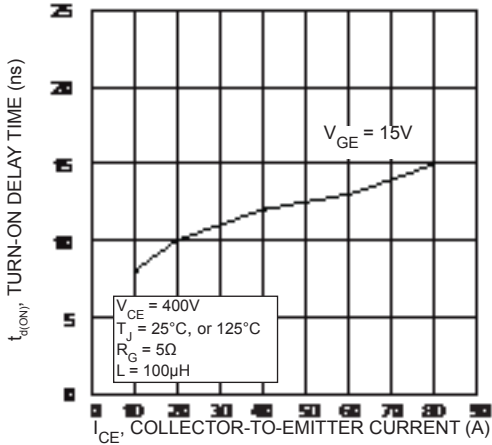


FIGURE 9, Turn-On Delay Time vs Collector Current

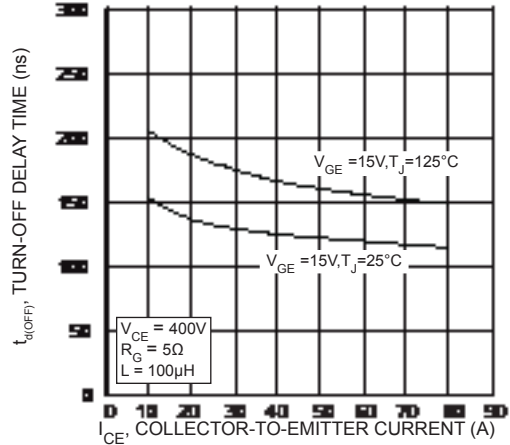


FIGURE 10, Turn-Off Delay Time vs Collector Current

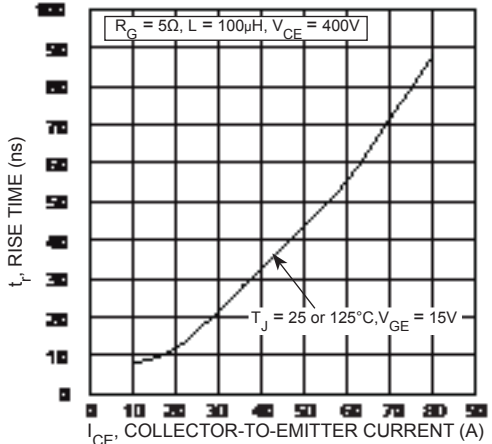


FIGURE 11, Current Rise Time vs Collector Current

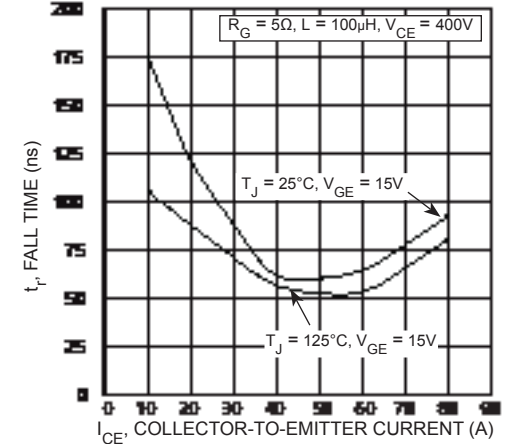


FIGURE 12, Current Fall Time vs Collector Current

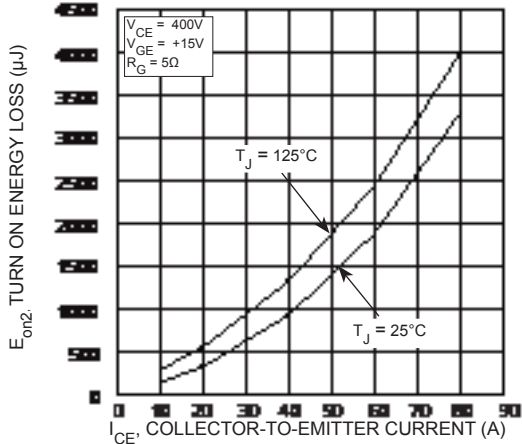


FIGURE 13, Turn-On Energy Loss vs Collector Current

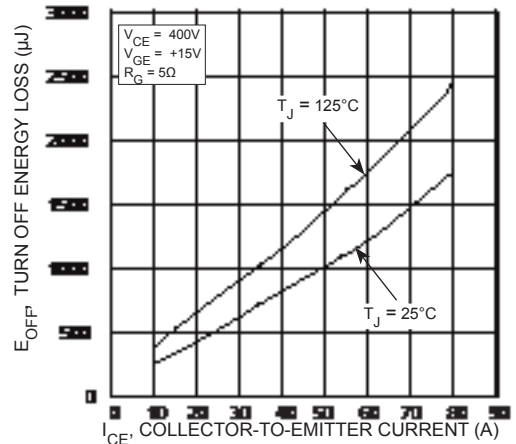


FIGURE 14, Turn-Off Energy Loss vs Collector Current

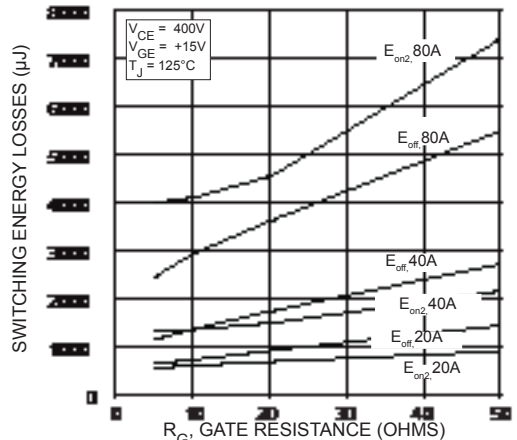


FIGURE 15, Switching Energy Losses vs Gate Resistance

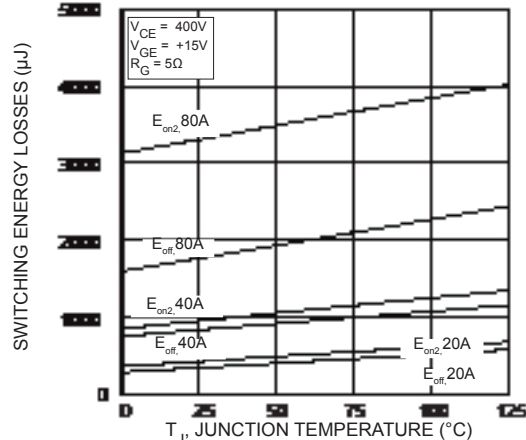
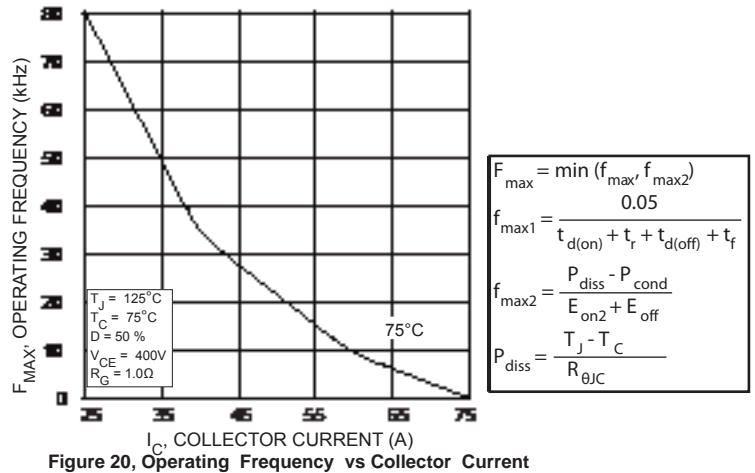
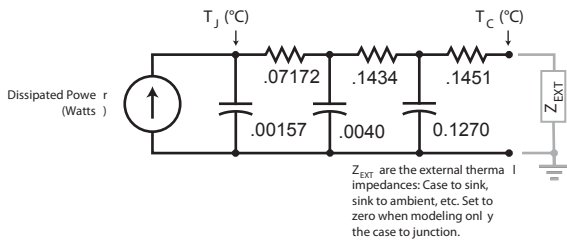
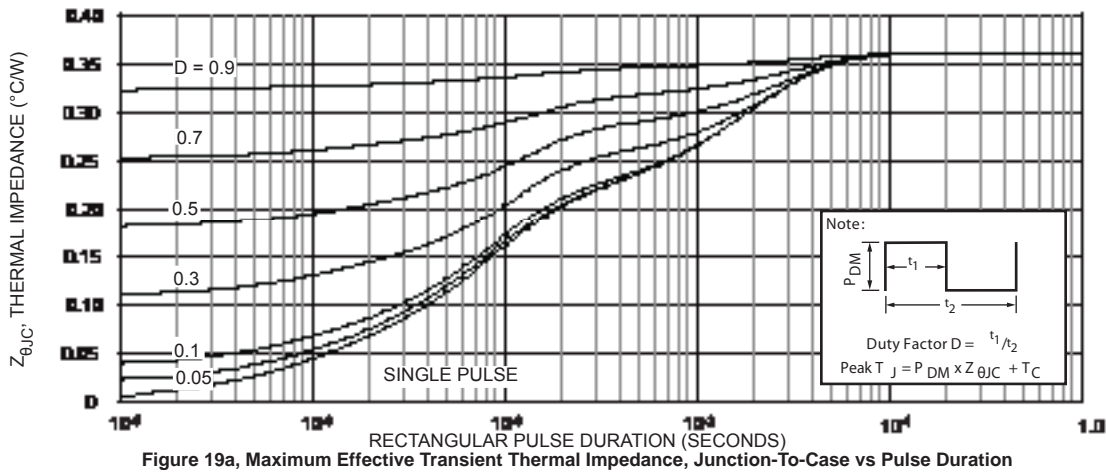
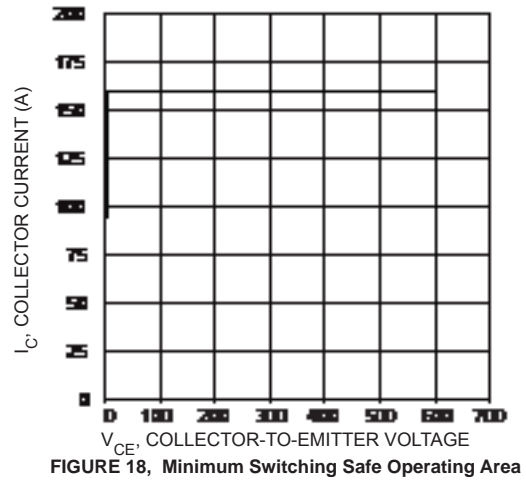
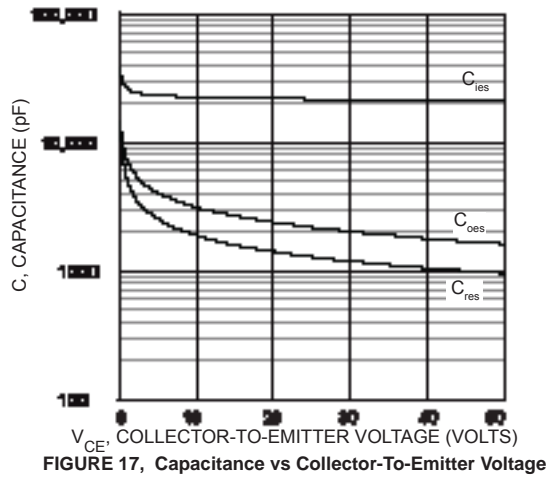


FIGURE 16, Switching Energy Losses vs Junction Temperature



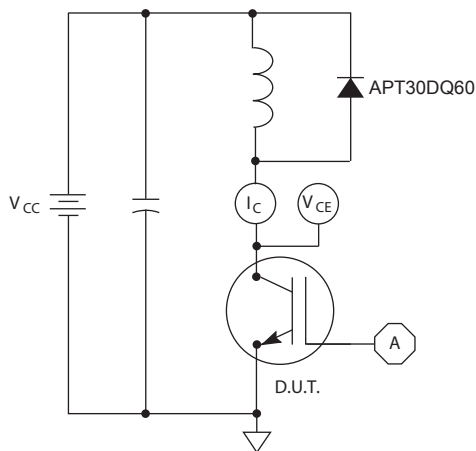


Figure 21, Inductive Switching Test Circuit

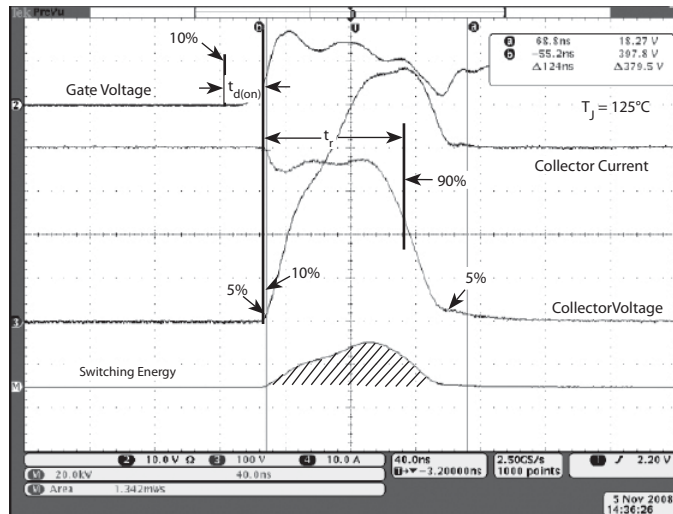


Figure 22, Turn-on Switching Waveforms and Definitions

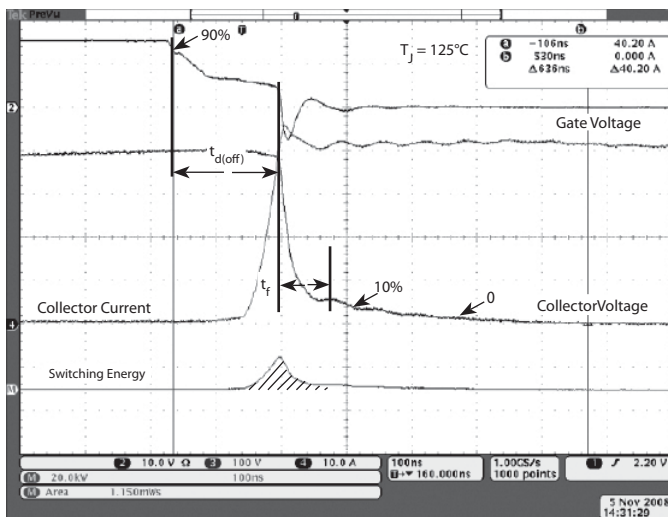
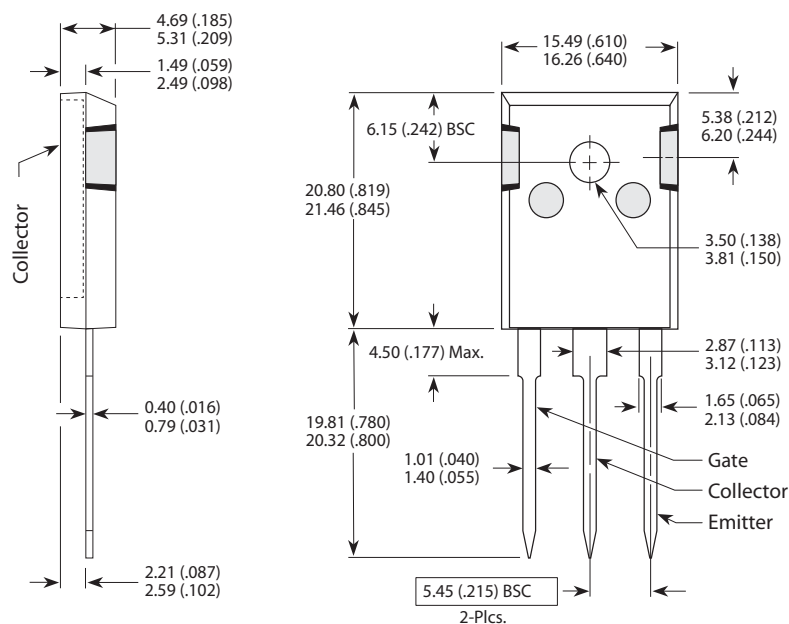


Figure 23, Turn-off Switching Waveforms and Definitions

TO-247 (B) Package Outline



Dimensions in Millimeters and (Inches)